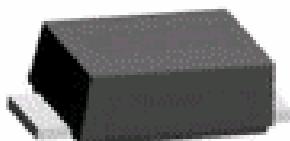


Features

- ◊ Glass passivated device
- ◊ Ideal for surface mounted applications
- ◊ Low leakage current
- ◊ Metallurgically bonded construction
- ◊ High temperature soldering:
250 °C /10 seconds at terminals

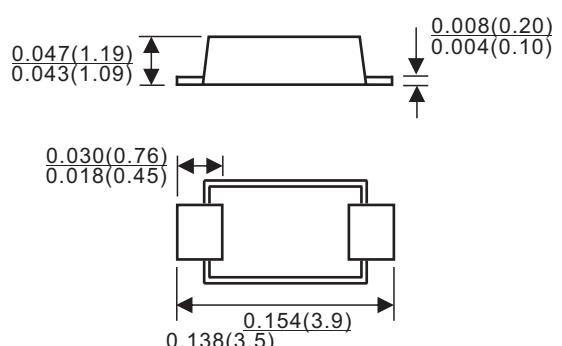
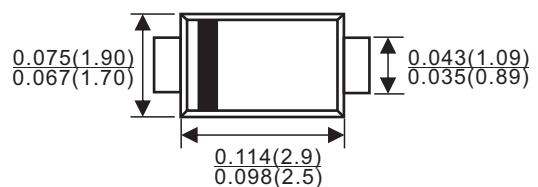
Mechanical Data

- ◊ Case: JEDEC SOD-123FL, molded plastic over passivated chip
- ◊ Polarity: Color band denotes cathode end
- ◊ Weight: 0.003 ounces, 0.01 gram
- ◊ Mounting position: Any



**REVERSE VOLTAGE: 100 - 200 V
CURRENT: 1.0 A**

SOD-123FL



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

ABSOLUTE RATINGS

		ES07B	ES07D	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	100	200	V
Maximum RMS voltage	V_{RMS}	70	140	V
Maximum DC blocking voltage	V_{DC}	100	200	V
Maximum average forward rectified current $T_A=65$ °C (NOTE 1)	$I_{(AV)}$	1.0		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load $T_L=25$ °C	I_{FSM}	30		A
Typical thermal resistance (NOTE 2)	R_{J0A}	180		K/W
Maximum reverse recovery time (NOTE 3)	t_{rr}	25		ns
Operating temperature range	T_j	-55 --- +150		
Storage temperature range	T_{STG}	-55 --- +150		

NOTES: 1. Averaged over any 20 ms period.

2. Thermal resistance junction to ambient, 6.0 mm² copper pads to each terminal.

3. Measured with $I_F=0.5A$, $I_R=1A$, $I_{rr}=0.25A$.

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Min	Typ.	Max.	Unit
Maximum instantaneous (NOTE 4) forward voltage at 1.0A	V_F	-	-	0.98	V
Maximum DC reverse current @ $T_A=25$ at rated DC blocking voltage @ $T_A=125$	I_R	- -	- -	10 100	μA
Typical junction capacitance (NOTE 5)	C_j	-	4	-	pF

NOTES: 4.Pulse test:300 μs pulse width,1% duty cycle.

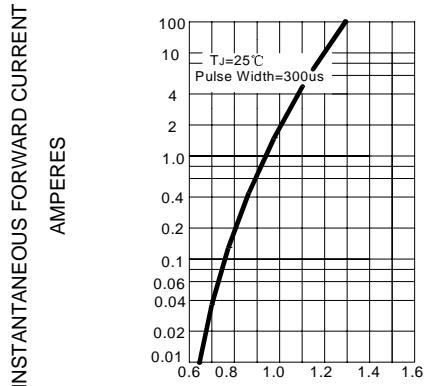
5.Measured at 1.0MHz and applied average voltage of 4.0V DC.

ELECTRICAL CHARACTERISTICS

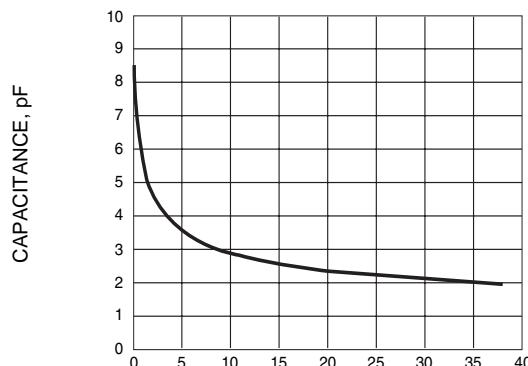
Parameter	Symbol	Min	Typ.	Max.	Unit
Maximum instantaneous (NOTE 4) forward voltage at 1.0A	V_F	-	-	0.98	V
Maximum DC reverse current @ $T_A=25$ at rated DC blocking voltage @ $T_A=125$	I_R	-	-	10 100	μA
Typical junction capacitance (NOTE 5)	C_j	-	4	-	pF

NOTES: 4.Pulse test:300 μ s pulse width,1% duty cycle.

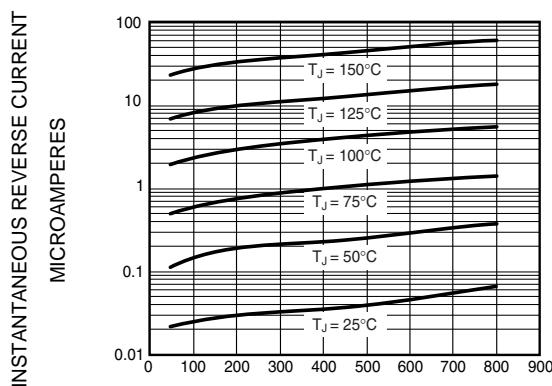
5.Measured at 1.0MHz and applied average voltage of 4.0V DC.

Ratings AND Characteristic Curves**FIG.1 – TYPICAL FORWARD CHARACTERISTIC**

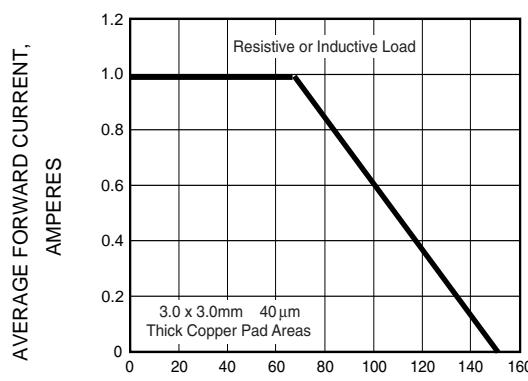
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.2 – TYPICAL JUNCTION CAPACITANCE

REVERSE VOLTAGE, VOLTS

FIG.3 – TYPICAL INSTANTANEOUS REVERSE CHARACTERISTICS

INSTANTANEOUS REVERSE VOLTAGE, VOLTS

FIG.4 – FORWARD DERATING CURVE

AMBIENT TEMPERATURE, °C